

APSEMI PhotoRelays

APSEMI Photorelays are the most reliable, technically advanced logic-to-power interface devices. Their basic function is to take a low current signal from a microprocessor to control the switching of both AC and DC loads, while providing an isolation barrier between logic and power. While this function is common to all relays, Photorelays provide distinct advantages over their mechanical counterparts including:

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI

- resistant to vibration and impact AC or DC load
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Applications

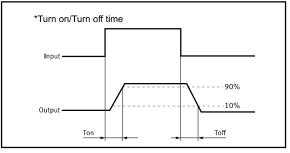
These advantages make APSEI Photorelays the ideal choice for:

- Telecom/Datacom switching .
- Multiplexers •
- Meter reading systems •
- Data acquisition
- Medical equipment .
- Battery monitoring •
- I/O Sub-Systems •

- Robotics Aerospace
- Home/Safety security systems
- Process Control
- **Energy Management** •
- Reed Relay EMR Replacement .
- Programmable Controllers

TPYES

Category	Output Rating		Bookago	Part No.	Pooking Quantity	
	Load Voltage	Load Current	Package	Fall NO.	Packing Quantity	
AC/DC	60V	1100mA	DIP-8	APW252G1E	50pcs /tube	
			SMD-8	APW252G1EH	1000pcs /reel	



switching

• No have voltaic arc, bounce, and noise More

- Small package size

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Absolute Maximum Ratings (Ta = 25°C)

	Item	Symbol	Va l ue	Units	Note
	Continuous LED Current	F	50	mA	
Input	Peak LED Current	IFP	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	Pin	75	mW	
Output	Load Voltage	VL	60	V(AC peak or DC)	
	Load Current	I.	1.1	А	
	Peak Load Current	Peak	2.5	А	100ms(1 pulse)
	Output Power Dissipation	Pout	450	mW	
Total Powe	Total Power Dissipation		500	mW	
I/O Breakdown Voltage		Vi/o	3750	Vrms	RH=60%, 1min
Operating Temperature		Topr	-40 to 85	°C	
Storage Temperature		Tstg	-40 to 100	°C	
Pin Soldering Temperature		Tsol	260	°C	10 sec max.

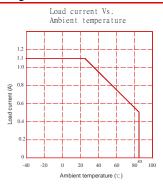
Electrical Characteristics (Ta = 25°C)

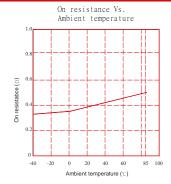
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions	
	LED Forward Voltage	VF		1.2	1.4	V	l⊧=10mA	
Input	Operation LED Current	Fon		0.5	3.0	mA		
	Recovery LED Current	Foff		0.35	0.5	mA		
	Recovery LED Voltage	VFoff	0.5			V		
							l⊧=5mA,I∟=100mA,	
	On-Resistance	Ron		0.27	0.7	Ω	Time to flow is within 1 sec.	
Output	Off-State Leakage	Leak			1	uA	V₋=Rating	
	Current	Louix						
	Output Capacitance	Cout		115		pF	V∟=0, f=1MHz	
Transmis	Turn-On Time	Ton		1.5	5.0	ms	l⊧=5mA, l∟=100mA,	
sion	Turn-Off Time	Toff		0.05	2.0	ms		
Coupled	I/O Isolation Resistance	Ri⁄o	10 ¹⁰			Ω	DC500V	
Coupled	I/O Capacitance	Сі/о		0.8	1.5	pF	f=1MHz	

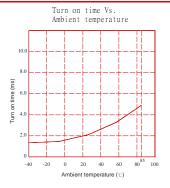
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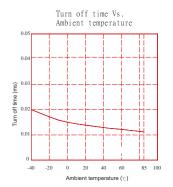
2 Form A APW252G1E_G1EH SMD-8 / DIP-8 Load Voltage:60V Load Current:1100mA

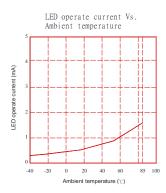
Engineering Data

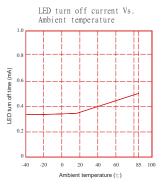




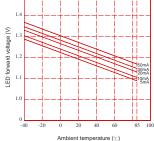




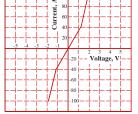


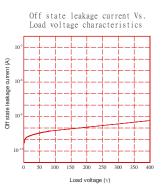


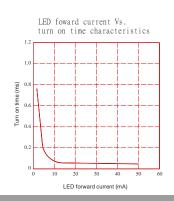
LED forward voltage Vs. Ambient temperature

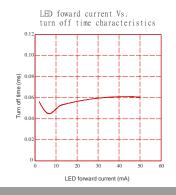


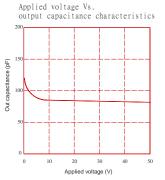








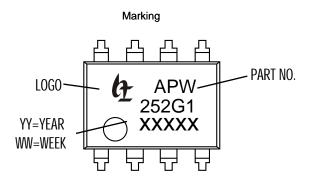




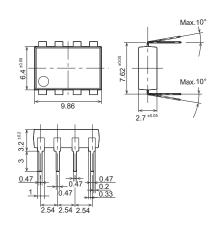
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Dimensions and DIP-8 Package Unit: mm

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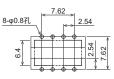


Through hole terminal type



Lable

PC board pattern (Bottom view)



DIP Tape dimensions Unit : mm

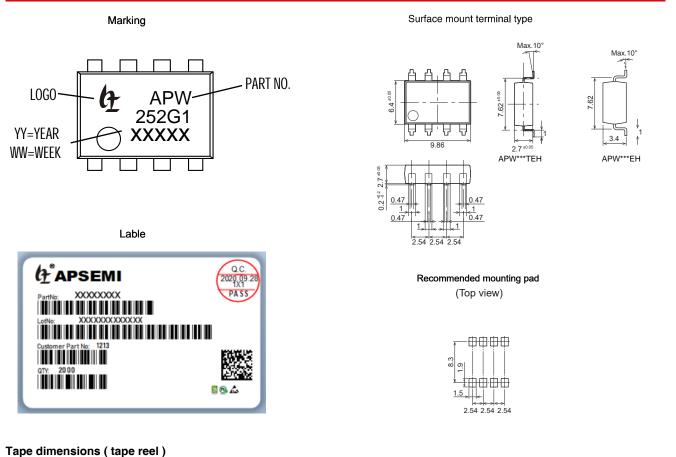
Devices are packaged in a tube so that pin No. 1 is on the stopper B side. Observe correct orientation when mounting them on PC boards.

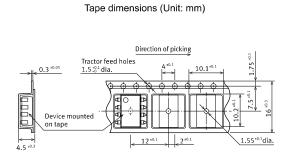


Dimensions and SMD-8 Package Unit: mm

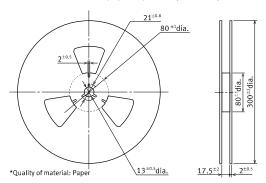
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Dimensions of paper tape reel (Unit: mm)

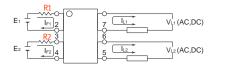


APW252G1E_G1EH



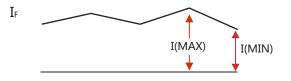
Using Methods

Examples of resistance value to control LED forward current (IF=5mA)



E1 E2	R1 R2(Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA , at I(MIN) ,and less than 30mA , at I(MAX).



Recommended Operating Conditions

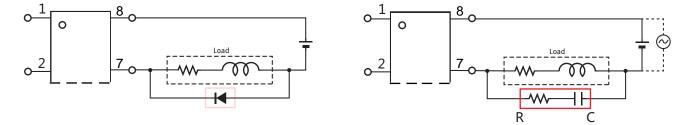
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	١ _F	5.0	7.0	30	mA

Protection Circuit

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.

CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.



When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.

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